

Welcome to [E-XFL.COM](https://www.e-xfl.com)

What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Not For New Designs
Core Processor	R8C
Core Size	16-Bit
Speed	20MHz
Connectivity	I ² C, LINbus, SIO, SSU, UART/USART
Peripherals	POR, Voltage Detect, WDT
Number of I/O	41
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	2K x 8
Voltage - Supply (Vcc/Vdd)	2.2V ~ 5.5V
Data Converters	A/D 12x10b
Oscillator Type	Internal
Operating Temperature	-20°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	52-LQFP
Supplier Device Package	52-LQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f21256snfp-x6

1. Overview

These MCUs are fabricated using a high-performance silicon gate CMOS process, embedding the R8C/Tiny Series CPU core, and are packaged in a 52-pin molded-plastic LQFP or a 64-pin molded-plastic FLGA. It implements sophisticated instructions for a high level of instruction efficiency. With 1 Mbyte of address space, they are capable of executing instructions at high speed.

Furthermore, the R8C/25 Group has on-chip data flash (1 KB x 2 blocks).

The difference between the R8C/24 Group and R8C/25 Group is only the presence or absence of data flash. Their peripheral functions are the same.

1.1 Applications

Electronic household appliances, office equipment, audio equipment, consumer products, etc.

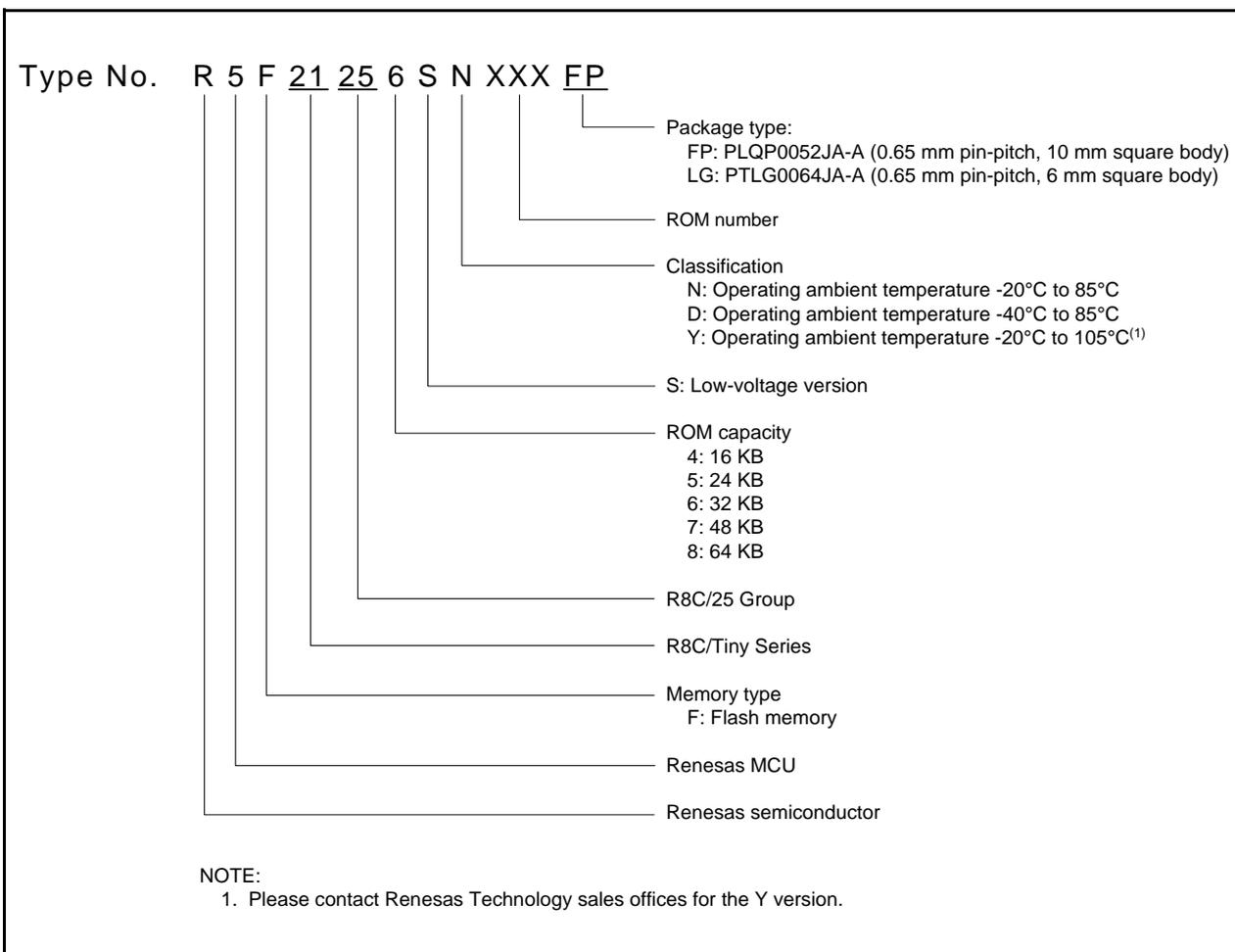


Figure 1.3 Type Number, Memory Size, and Package of R8C/25 Group

Table 1.6 Pin Name Information by Pin Number

Pin Number	Control Pin	Port	I/O Pin Functions for of Peripheral Modules					
			Interrupt	Timer	Serial Interface	Clock Synchronous Serial I/O with Chip Select	I ² C bus Interface	A/D Converter
2		P3_5				SSCK	SCL	
3		P3_3				SSI		
4		P3_4				SCS	SDA	
5	MODE							
6	XCIN	P4_3						
7	XCOU	P4_4						
8	RESET							
9	XOUT	P4_7						
10	VSS/AVSS							
11	XIN	P4_6						
12	VCC/AVCC							
13		P2_7		TRDIOD1				
14		P2_6		TRDIOC1				
15		P2_5		TRDIOB1				
16		P2_4		TRDIOA1				
17		P2_3		TRDIOD0				
18		P2_2		TRDIOC0				
19		P2_1		TRDIOB0				
20		P2_0		TRDIOA0/TRDCLK				
21		P1_7	INT1	TRAIO				
22		P1_6			CLK0			
23		P1_5	(INT1) ⁽¹⁾	(TRAIO) ⁽¹⁾	RXD0			
24		P1_4			TXD0			
25		P1_3	K3					AN11
27		P4_5	INT0	INT0				
28		P6_6	INT2		TXD1			
29		P6_7	INT3		RXD1			
30		P1_2	K2					AN10
31		P1_1	K1					AN9
32		P1_0	K0					AN8
33		P3_1		TRBO				
34		P3_0		TRA0				
35		P6_5			CLK1			
36		P6_4						
37		P6_3						
38		P0_7						AN0
41		P0_6						AN1
42		P0_5						AN2
43		P0_4						AN3
44	VREF	P4_2						
45		P6_0		TRE0				
46		P6_2						
47		P6_1						
48		P0_3						AN4
49		P0_2						AN5
50		P0_1						AN6
51		P0_0						AN7
52		P3_7				SSO		

NOTE:

1. Can be assigned to the pin in parentheses by a program.

2. Central Processing Unit (CPU)

Figure 2.1 shows the CPU Registers. The CPU contains 13 registers. R0, R1, R2, R3, A0, A1, and FB configure a register bank. There are two sets of register bank.

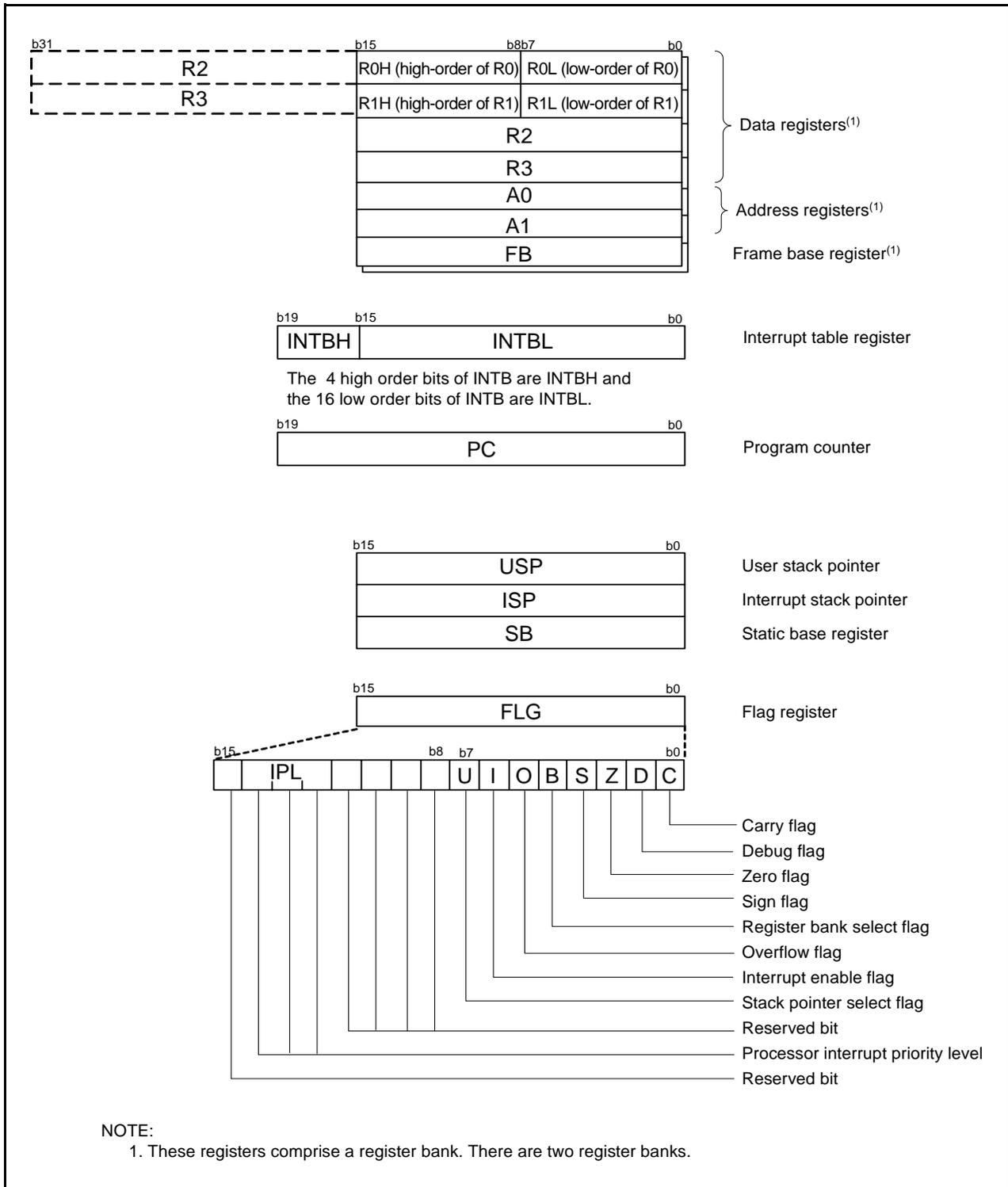


Figure 2.1 CPU Registers

3.2 R8C/25 Group

Figure 3.2 is a Memory Map of R8C/25 Group. The R8C/25 group has 1 Mbyte of address space from addresses 00000h to FFFFFh.

The internal ROM (program ROM) is allocated lower addresses, beginning with address 0FFFFh. For example, a 48-Kbyte internal ROM area is allocated addresses 04000h to 0FFFFh.

The fixed interrupt vector table is allocated addresses 0FFDCh to 0FFFFh. They store the starting address of each interrupt routine.

The internal ROM (data flash) is allocated addresses 02400h to 02BFFh.

The internal RAM area is allocated higher addresses, beginning with address 00400h. For example, a 2-Kbyte internal RAM is allocated addresses 00400h to 00BFFh. The internal RAM is used not only for storing data but also for calling subroutines and as stacks when interrupt requests are acknowledged.

Special function registers (SFRs) are allocated addresses 00000h to 002FFh. The peripheral function control registers are allocated here. All addresses within the SFR, which have nothing allocated are reserved for future use and cannot be accessed by users.

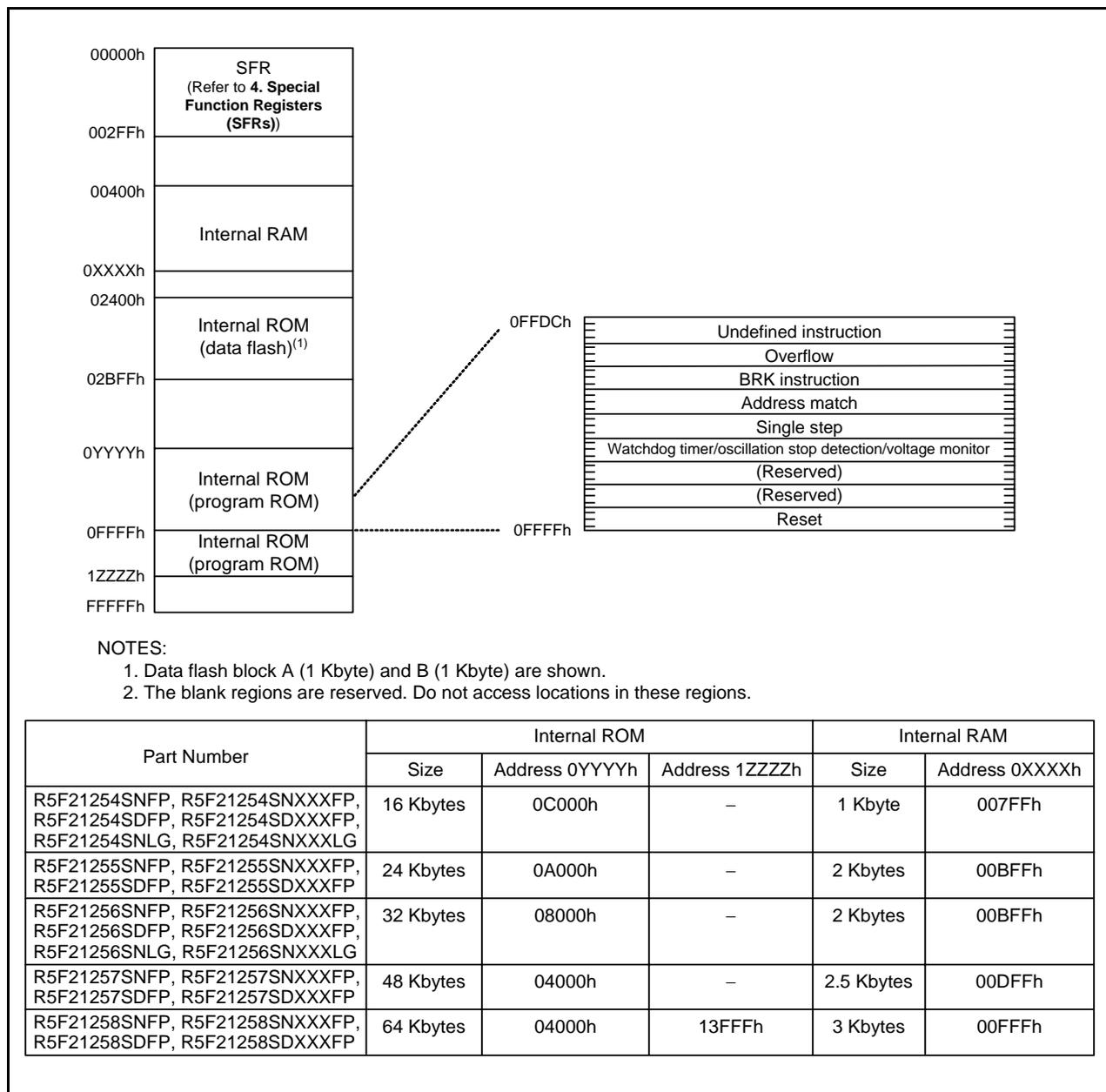


Figure 3.2 Memory Map of R8C/25 Group

4. Special Function Registers (SFRs)

An SFR (special function register) is a control register for a peripheral function. Tables 4.1 to 4.7 list the special function registers.

Table 4.1 SFR Information (1)(1)

Address	Register	Symbol	After reset
0000h			
0001h			
0002h			
0003h			
0004h	Processor Mode Register 0	PM0	00h
0005h	Processor Mode Register 1	PM1	00h
0006h	System Clock Control Register 0	CM0	01101000b
0007h	System Clock Control Register 1	CM1	00100000b
0008h			
0009h			
000Ah	Protect Register	PRCR	00h
000Bh			
000Ch	Oscillation Stop Detection Register	OCD	00000100b
000Dh	Watchdog Timer Reset Register	WDTR	XXh
000Eh	Watchdog Timer Start Register	WDTS	XXh
000Fh	Watchdog Timer Control Register	WDC	00X11111b
0010h	Address Match Interrupt Register 0	RMAD0	00h
0011h			00h
0012h			00h
0013h	Address Match Interrupt Enable Register	AIER	00h
0014h	Address Match Interrupt Register 1	RMAD1	00h
0015h			00h
0016h			00h
0017h			
0018h			
0019h			
001Ah			
001Bh			
001Ch	Count Source Protection Mode Register	CSPR	00h 10000000b ⁽⁶⁾
001Dh			
001Eh			
001Fh			
0020h			
0021h			
0022h			
0023h	High-Speed On-Chip Oscillator Control Register 0	FRA0	00h
0024h	High-Speed On-Chip Oscillator Control Register 1	FRA1	When shipping
0025h	High-Speed On-Chip Oscillator Control Register 2	FRA2	00h
0026h			
0027h			
0028h	Clock Prescaler Reset Flag	CPSRF	00h
0029h	High-Speed On-Chip Oscillator Control Register 4	FRA4	When shipping
002Ah			
002Bh	High-Speed On-Chip Oscillator Control Register 6	FRA6	When shipping
002Ch	High-Speed On-Chip Oscillator Control Register 7	FRA7	When shipping
0030h			
0031h	Voltage Detection Register 1 ⁽²⁾	VCA1	00001000b
0032h	Voltage Detection Register 2 ⁽²⁾	VCA2	00h ⁽³⁾ 00100000b ⁽⁴⁾
0033h			
0034h			
0035h			
0036h	Voltage Monitor 1 Circuit Control Register ⁽⁵⁾	VW1C	00001000b
0037h	Voltage Monitor 2 Circuit Control Register ⁽⁵⁾	VW2C	00h
0038h	Voltage Monitor 0 Circuit Control Register ⁽²⁾	VW0C	0000X000b ⁽³⁾ 0100X001b ⁽⁴⁾
0039h			
003Ah			
003Eh			
003Fh			

X: Undefined

NOTES:

1. The blank regions are reserved. Do not access locations in these regions.
2. Software reset, watchdog timer reset, and voltage monitor 1 reset or voltage monitor 2 reset do not affect this register.
3. The LVDOON bit in the OFS register is set to 1 and hardware reset.
4. Power-on reset, voltage monitor 0 reset or the LVDOON bit in the OFS register is set to 0, and hardware reset.
5. Software reset, watchdog timer reset, and voltage monitor 1 reset or voltage monitor 2 reset do not affect b2 and b3.
6. The CSPROINI bit in the OFS register is set to 0.

Table 4.2 SFR Information (2)⁽¹⁾

Address	Register	Symbol	After reset
0040h			
0041h			
0042h			
0043h			
0044h			
0045h			
0046h			
0047h			
0048h	Timer RD0 Interrupt Control Register	TRD0IC	XXXXX000b
0049h	Timer RD1 Interrupt Control Register	TRD1IC	XXXXX000b
004Ah	Timer RE Interrupt Control Register	TREIC	XXXXX000b
004Bh			
004Ch			
004Dh	Key Input Interrupt Control Register	KUPIC	XXXXX000b
004Eh	A/D Conversion Interrupt Control Register	ADIC	XXXXX000b
004Fh	SSU/IIC Interrupt Control Register ⁽²⁾	SSUIC / IICIC	XXXXX000b
0050h			
0051h	UART0 Transmit Interrupt Control Register	S0TIC	XXXXX000b
0052h	UART0 Receive Interrupt Control Register	S0RIC	XXXXX000b
0053h	UART1 Transmit Interrupt Control Register	S1TIC	XXXXX000b
0054h	UART1 Receive Interrupt Control Register	S1RIC	XXXXX000b
0055h	INT2 Interrupt Control Register	INT2IC	XX00X000b
0056h	Timer RA Interrupt Control Register	TRAIC	XXXXX000b
0057h			
0058h	Timer RB Interrupt Control Register	TRBIC	XXXXX000b
0059h	INT1 Interrupt Control Register	INT1IC	XX00X000b
005Ah	INT3 Interrupt Control Register	INT3IC	XX00X000b
005Bh			
005Ch			
005Dh	INT0 Interrupt Control Register	INT0IC	XX00X000b
005Eh			
005Fh			
0060h			
0061h			
0062h			
0063h			
0064h			
0065h			
0066h			
0067h			
0068h			
0069h			
006Ah			
006Bh			
006Ch			
006Dh			
006Eh			
006Fh			
0070h			
0071h			
0072h			
0073h			
0074h			
0075h			
0076h			
0077h			
0078h			
0079h			
007Ah			
007Bh			
007Ch			
007Dh			
007Eh			
007Fh			

X: Undefined

NOTES:

1. The blank regions are reserved. Do not access locations in these regions.
2. Selected by the IICSEL bit in the PMR register.

Table 4.4 SFR Information (4)⁽¹⁾

Address	Register	Symbol	After reset
00C0h	A/D Register	AD	XXh
00C1h			XXh
00C2h			
00C3h			
00C4h			
00C5h			
00C6h			
00C7h			
00C8h			
00C9h			
00CAh			
00CBh			
00CCh			
00CDh			
00CEh			
00CFh			
00D0h			
00D1h			
00D2h			
00D3h			
00D4h	A/D Control Register 2	ADCON2	00h
00D5h			
00D6h	A/D Control Register 0	ADCON0	00h
00D7h	A/D Control Register 1	ADCON1	00h
00D8h			
00D9h			
00DAh			
00DBh			
00DCh			
00DDh			
00DEh			
00DFh			
00E0h	Port P0 Register	P0	XXh
00E1h	Port P1 Register	P1	XXh
00E2h	Port P0 Direction Register	PD0	00h
00E3h	Port P1 Direction Register	PD1	00h
00E4h	Port P2 Register	P2	XXh
00E5h	Port P3 Register	P3	XXh
00E6h	Port P2 Direction Register	PD2	00h
00E7h	Port P3 Direction Register	PD3	00h
00E8h	Port P4 Register	P4	XXh
00E9h			
00EAh	Port P4 Direction Register	PD4	00h
00EBh			
00ECh	Port P6 Register	P6	XXh
00EDh			
00EEh	Port P6 Direction Register	PD6	00h
00EFh			
00F0h			
00F1h			
00F2h			
00F3h			
00F4h	Port P2 Drive Capacity Control Register	P2DRR	00h
00F5h	UART1 Function Select Register	U1SR	XXh
00F6h			
00F7h			
00F8h	Port Mode Register	PMR	00h
00F9h	External Input Enable Register	INTEN	00h
00FAh	INT Input Filter Select Register	INTF	00h
00FBh	Key Input Enable Register	KIEN	00h
00FCh	Pull-Up Control Register 0	PUR0	00h
00FDh	Pull-Up Control Register 1	PUR1	XX00XX00b
00FEh			
00FFh			

X: Undefined

NOTE:

1. The blank regions are reserved. Do not access locations in these regions.

Table 4.6 SFR Information (6)⁽¹⁾

Address	Register	Symbol	After reset
0140h	Timer RD Control Register 0	TRDCR0	00h
0141h	Timer RD I/O Control Register A0	TRDIORA0	10001000b
0142h	Timer RD I/O Control Register C0	TRDIORC0	10001000b
0143h	Timer RD Status Register 0	TRDSR0	11100000b
0144h	Timer RD Interrupt Enable Register 0	TRDIER0	11100000b
0145h	Timer RD PWM Mode Output Level Control Register 0	TRDPOCR0	11111000b
0146h	Timer RD Counter 0	TRD0	00h
0147h			00h
0148h	Timer RD General Register A0	TRDGRA0	FFh
0149h			FFh
014Ah	Timer RD General Register B0	TRDGRB0	FFh
014Bh			FFh
014Ch	Timer RD General Register C0	TRDGRC0	FFh
014Dh			FFh
014Eh	Timer RD General Register D0	TRDGRD0	FFh
014Fh			FFh
0150h	Timer RD Control Register 1	TRDCR1	00h
0151h	Timer RD I/O Control Register A1	TRDIORA1	10001000b
0152h	Timer RD I/O Control Register C1	TRDIORC1	10001000b
0153h	Timer RD Status Register 1	TRDSR1	11000000b
0154h	Timer RD Interrupt Enable Register 1	TRDIER1	11100000b
0155h	Timer RD PWM Mode Output Level Control Register 1	TRDPOCR1	11111000b
0156h	Timer RD Counter 1	TRD1	00h
0157h			00h
0158h	Timer RD General Register A1	TRDGRA1	FFh
0159h			FFh
015Ah	Timer RD General Register B1	TRDGRB1	FFh
015Bh			FFh
015Ch	Timer RD General Register C1	TRDGRC1	FFh
015Dh			FFh
015Eh	Timer RD General Register D1	TRDGRD1	FFh
015Fh			FFh
0160h			
0161h			
0162h			
0163h			
0164h			
0165h			
0166h			
0167h			
0168h			
0169h			
016Ah			
016Bh			
016Ch			
016Dh			
016Eh			
016Fh			
0170h			
0171h			
0172h			
0173h			
0174h			
0175h			
0176h			
0177h			
0178h			
0179h			
017Ah			
017Bh			
017Ch			
017Dh			
017Eh			
017Fh			

X: Undefined

NOTE:

1. The blank regions are reserved. Do not access locations in these regions.

Table 5.10 High-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
fOCO40M	High-speed on-chip oscillator frequency temperature • supply voltage dependence	V _{CC} = 4.75 to 5.25 V 0°C ≤ T _{opr} ≤ 60°C ⁽²⁾	39.2	40	40.8	MHz
		V _{CC} = 4.5 to 5.5 V -20°C ≤ T _{opr} ≤ 85°C	38.8	40	40.8	MHz
		V _{CC} = 4.5 to 5.5 V -40°C ≤ T _{opr} ≤ 85°C	38.4	40	40.8	MHz
		V _{CC} = 3.0 to 5.5 V -20°C ≤ T _{opr} ≤ 85°C ⁽²⁾	38.8	40	41.2	MHz
		V _{CC} = 3.0 to 5.5 V -40°C ≤ T _{opr} ≤ 85°C ⁽²⁾	38.4	40	41.6	MHz
		V _{CC} = 2.7 to 5.5 V -20°C ≤ T _{opr} ≤ 85°C ⁽²⁾	38	40	42	MHz
		V _{CC} = 2.7 to 5.5 V -40°C ≤ T _{opr} ≤ 85°C ⁽²⁾	37.6	40	42.4	MHz
		V _{CC} = 2.2 to 5.5 V -20°C ≤ T _{opr} ≤ 85°C ⁽³⁾	35.2	40	44.8	MHz
		V _{CC} = 2.2 to 5.5 V -40°C ≤ T _{opr} ≤ 85°C ⁽³⁾	34	40	46	MHz
	High-speed on-chip oscillator frequency when correction value in FRA7 register is written to FRA1 register ⁽⁴⁾	V _{CC} = 5.0 V, T _{opr} = 25°C	–	36.864		MHz
V _{CC} = 3.0 to 5.5 V -20°C ≤ T _{opr} ≤ 85°C		-3%	–	3%	%	
–	Value in FRA1 register after reset		08h	–	F7h	–
–	Oscillation frequency adjustment unit of high-speed on-chip oscillator	Adjust FRA1 register (value after reset) to -1	–	+0.3	–	MHz
–	Oscillation stability time		–	10	100	μs
–	Self power consumption at oscillation	V _{CC} = 5.0 V, T _{opr} = 25°C	–	400	–	μA

NOTES:

- V_{CC} = 2.2 to 5.5 V, T_{opr} = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.
- Standard values when the FRA1 register value after reset is assumed.
- Standard values when the corrected value of the FRA6 register has been written to the FRA1 register.
- This enables the setting errors of bit rates such as 9600 bps and 38400 bps to be 0% when the serial interface is used in UART mode.

Table 5.11 Low-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
fOCO-S	Low-speed on-chip oscillator frequency		30	125	250	kHz
–	Oscillation stability time		–	10	100	μs
–	Self power consumption at oscillation	V _{CC} = 5.0 V, T _{opr} = 25°C	–	15	–	μA

NOTE:

- V_{CC} = 2.2 to 5.5 V, T_{opr} = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.

Table 5.12 Power Supply Circuit Timing Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
t _d (P-R)	Time for internal power supply stabilization during power-on ⁽²⁾		1	–	2000	μs
t _d (R-S)	STOP exit time ⁽³⁾		–	–	150	μs

NOTES:

- The measurement condition is V_{CC} = 2.2 to 5.5 V and T_{opr} = 25°C.
- Waiting time until the internal power supply generation circuit stabilizes during power-on.
- Time until system clock supply starts after the interrupt is acknowledged to exit stop mode.

Table 5.14 Timing Requirements of I²C bus Interface(1)

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
t _{SCL}	SCL input cycle time		12t _{CYC} + 600 ⁽²⁾	–	–	ns
t _{SCLH}	SCL input “H” width		3t _{CYC} + 300 ⁽²⁾	–	–	ns
t _{SCLL}	SCL input “L” width		5t _{CYC} + 500 ⁽²⁾	–	–	ns
t _{sf}	SCL, SDA input fall time		–	–	300	ns
t _{SP}	SCL, SDA input spike pulse rejection time		–	–	1t _{CYC} ⁽²⁾	ns
t _{BUF}	SDA input bus-free time		5t _{CYC} ⁽²⁾	–	–	ns
t _{STAH}	Start condition input hold time		3t _{CYC} ⁽²⁾	–	–	ns
t _{STAS}	Retransmit start condition input setup time		3t _{CYC} ⁽²⁾	–	–	ns
t _{STOP}	Stop condition input setup time		3t _{CYC} ⁽²⁾	–	–	ns
t _{SDAS}	Data input setup time		1t _{CYC} + 20 ⁽²⁾	–	–	ns
t _{SDAH}	Data input hold time		0	–	–	ns

NOTES:

- V_{CC} = 2.2 to 5.5 V, V_{SS} = 0 V and T_{opr} = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.
- 1t_{CYC} = 1/f₁(s)

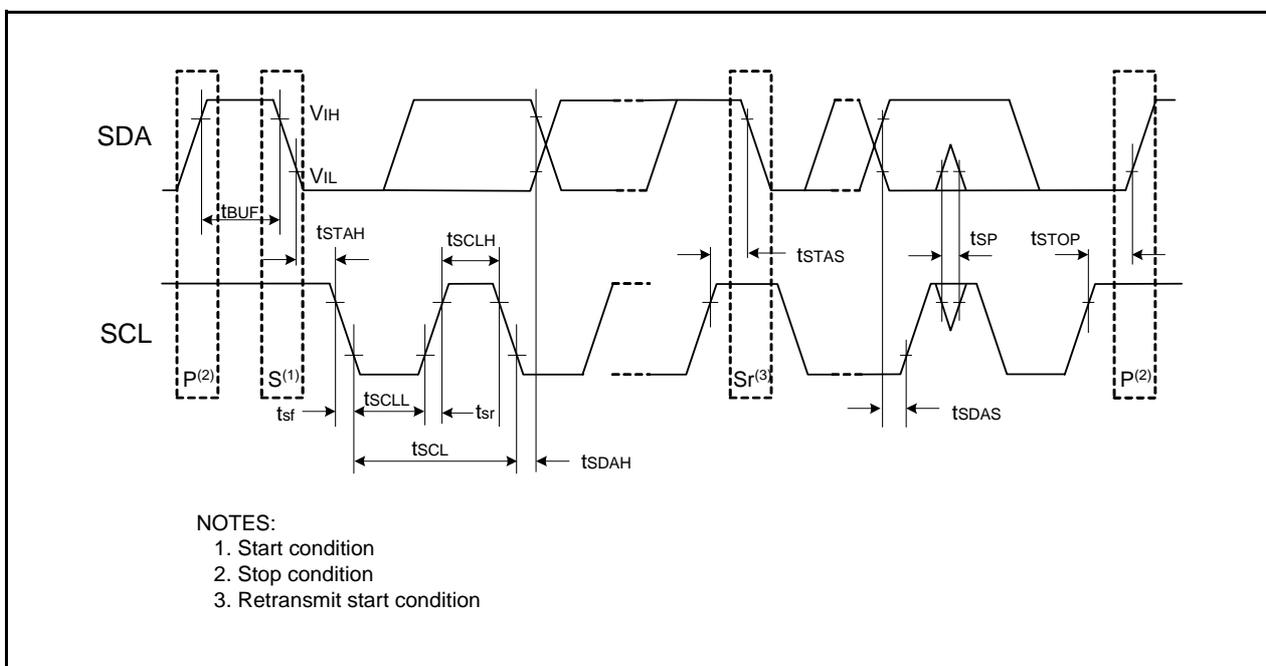
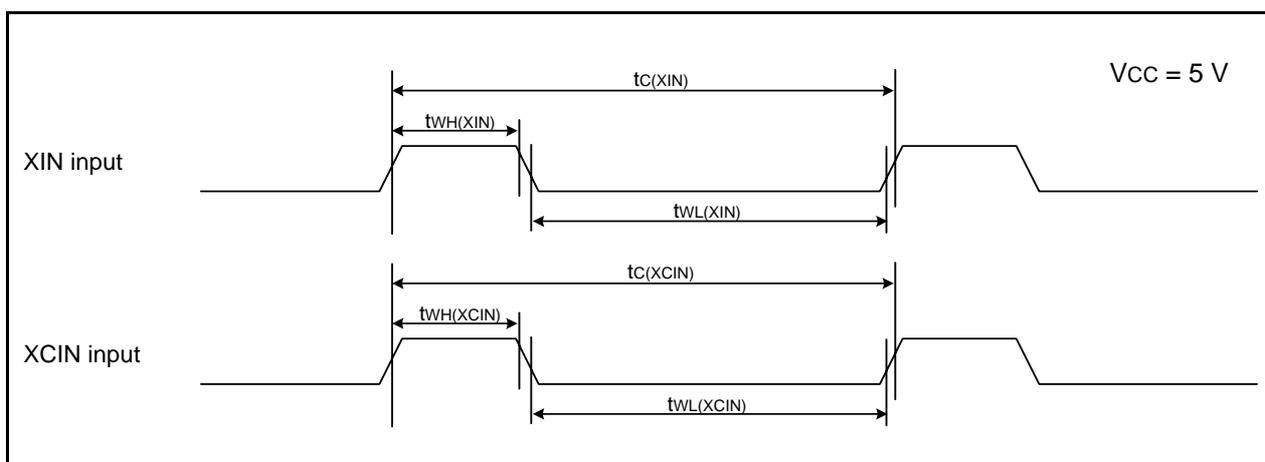


Figure 5.7 I/O Timing of I²C bus Interface

Timing Requirements**(Unless Otherwise Specified: $V_{CC} = 5\text{ V}$, $V_{SS} = 0\text{ V}$ at $T_{opr} = 25^\circ\text{C}$) [$V_{CC} = 5\text{ V}$]****Table 5.18 XIN Input, XCIN Input**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(XIN)}$	XIN input cycle time	50	–	ns
$t_{WH(XIN)}$	XIN input "H" width	25	–	ns
$t_{WL(XIN)}$	XIN input "L" width	25	–	ns
$t_{c(XCIN)}$	XCIN input cycle time	14	–	μs
$t_{WH(XCIN)}$	XCIN input "H" width	7	–	μs
$t_{WL(XCIN)}$	XCIN input "L" width	7	–	μs

**Figure 5.8 XIN Input and XCIN Input Timing Diagram when $V_{CC} = 5\text{ V}$** **Table 5.19 TRAIO Input**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TRAIO)}$	TRAIO input cycle time	100	–	ns
$t_{WH(TRAIO)}$	TRAIO input "H" width	40	–	ns
$t_{WL(TRAIO)}$	TRAIO input "L" width	40	–	ns

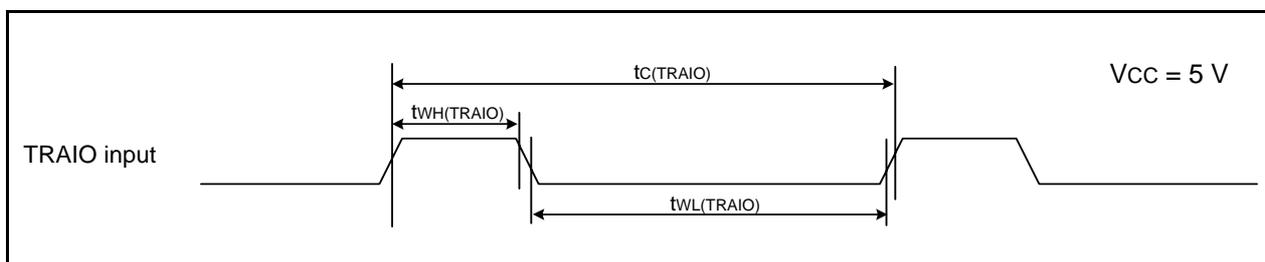
**Figure 5.9 TRAIO Input Timing Diagram when $V_{CC} = 5\text{ V}$**

Table 5.20 Serial Interface

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(CK)}$	CLKi input cycle time	200	–	ns
$t_{w(CKH)}$	CLKi input “H” width	100	–	ns
$t_{w(CKL)}$	CLKi input “L” width	100	–	ns
$t_{d(C-Q)}$	TXDi output delay time	–	50	ns
$t_{h(C-Q)}$	TXDi hold time	0	–	ns
$t_{su(D-C)}$	RXDi input setup time	50	–	ns
$t_{h(C-D)}$	RXDi input hold time	90	–	ns

i = 0 or 1

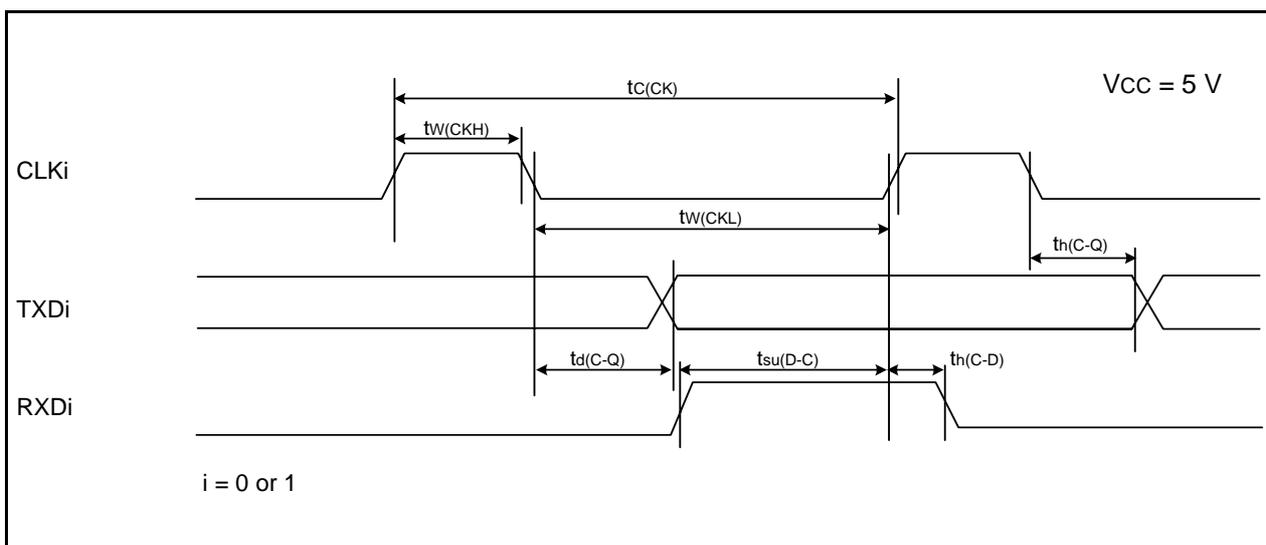


Figure 5.10 Serial Interface Timing Diagram when Vcc = 5 V

Table 5.21 External Interrupt \overline{INTi} (i = 0 to 3) Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(INH)}$	$\overline{INT0}$ input “H” width	250 ⁽¹⁾	–	ns
$t_{w(INL)}$	$\overline{INT0}$ input “L” width	250 ⁽²⁾	–	ns

NOTES:

1. When selecting the digital filter by the \overline{INTi} input filter select bit, use an \overline{INTi} input HIGH width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.
2. When selecting the digital filter by the \overline{INTi} input filter select bit, use an \overline{INTi} input LOW width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.

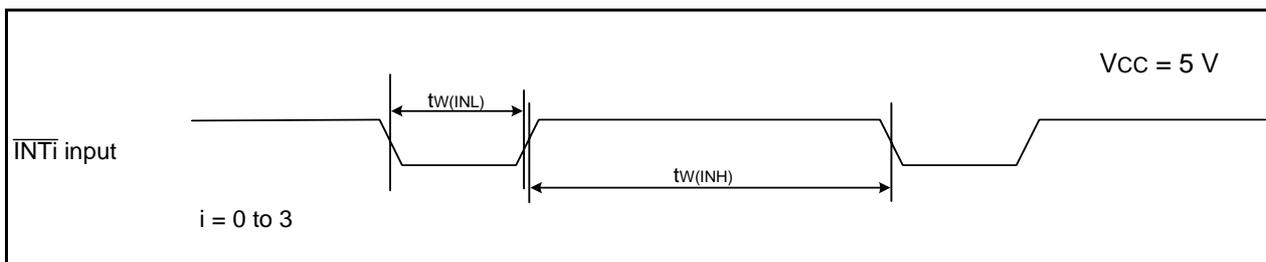


Figure 5.11 External Interrupt \overline{INTi} Input Timing Diagram when Vcc = 5 V

Table 5.22 Electrical Characteristics (3) [V_{CC} = 3 V]

Symbol	Parameter		Condition		Standard			Unit
					Min.	Typ.	Max.	
V _{OH}	Output "H" voltage	Except P2_0 to P2_7, XOUT	I _{OH} = -1 mA		V _{CC} - 0.5	–	V _{CC}	V
		P2_0 to P2_7	Drive capacity HIGH	I _{OH} = -5 mA	V _{CC} - 0.5	–	V _{CC}	V
			Drive capacity LOW	I _{OH} = -1 mA	V _{CC} - 0.5	–	V _{CC}	V
		XOUT	Drive capacity HIGH	I _{OH} = -0.1 mA	V _{CC} - 0.5	–	V _{CC}	V
			Drive capacity LOW	I _{OH} = -50 μA	V _{CC} - 0.5	–	V _{CC}	V
V _{OL}	Output "L" voltage	Except P2_0 to P2_7, XOUT	I _{OL} = 1 mA		–	–	0.5	V
		P2_0 to P2_7	Drive capacity HIGH	I _{OL} = 5 mA	–	–	0.5	V
			Drive capacity LOW	I _{OL} = 1 mA	–	–	0.5	V
		XOUT	Drive capacity HIGH	I _{OL} = 0.1 mA	–	–	0.5	V
			Drive capacity LOW	I _{OL} = 50 μA	–	–	0.5	V
V _{T+} -V _{T-}	Hysteresis	<u>INT0</u> , <u>INT1</u> , <u>INT2</u> , <u>INT3</u> , <u>KI0</u> , <u>KI1</u> , <u>KI2</u> , <u>KI3</u> , <u>TRAIO</u> , <u>RXD0</u> , <u>RXD1</u> , <u>CLK0</u> , <u>CLK1</u> , <u>SSI</u> , <u>SCL</u> , <u>SDA</u> , <u>SSO</u>			0.1	0.3	–	V
		<u>RESET</u>			0.1	0.4	–	V
I _{IH}	Input "H" current		V _I = 3 V, V _{CC} = 3V		–	–	4.0	μA
I _{IL}	Input "L" current		V _I = 0 V, V _{CC} = 3V		–	–	-4.0	μA
R _{PULLUP}	Pull-up resistance		V _I = 0 V, V _{CC} = 3V		66	160	500	kΩ
R _{FXIN}	Feedback resistance	XIN			–	3.0	–	MΩ
R _{FXCIN}	Feedback resistance	XCIN			–	18	–	MΩ
V _{RAM}	RAM hold voltage		During stop mode		1.8	–	–	V

NOTE:

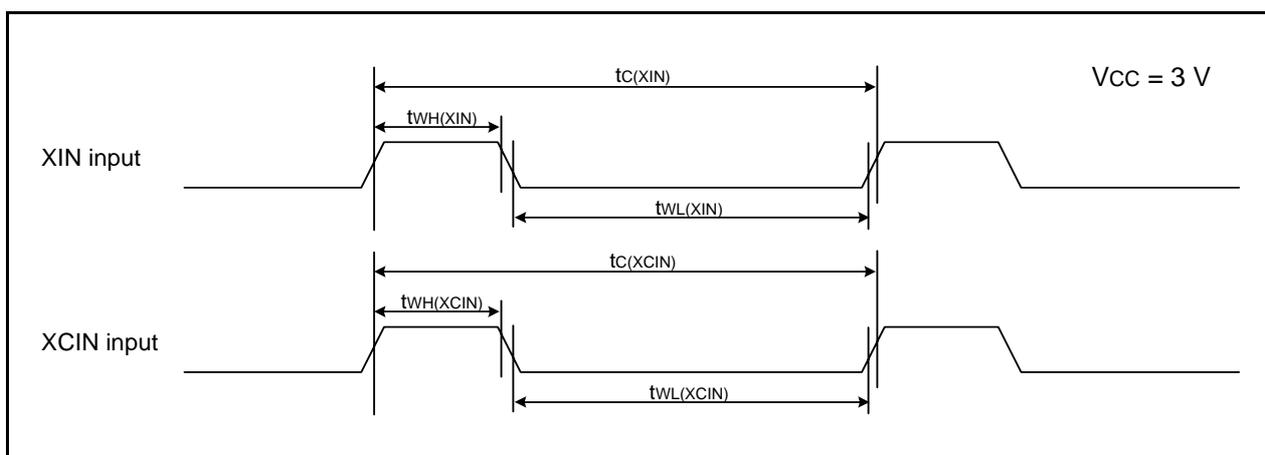
- V_{CC} = 2.7 to 3.3 V at T_{opr} = -20 to 85°C (N version) / -40 to 85°C (D version), f(XIN) = 10 MHz, unless otherwise specified.

**Table 5.23 Electrical Characteristics (4) [V_{CC} = 3 V]
(T_{opr} = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.)**

Symbol	Parameter	Condition	Standard			Unit	
			Min.	Typ.	Max.		
I _{CC}	Power supply current (V _{CC} = 2.7 to 3.3 V) Single-chip mode, output pins are open, other pins are V _{SS}	High-speed clock mode	XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	–	6	–	mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	2	–	mA
		High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on f _{OCO} = 10 MHz Low-speed on-chip oscillator on = 125 kHz No division	–	5	9	mA
			XIN clock off High-speed on-chip oscillator on f _{OCO} = 10 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	2	–	mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1	–	130	300	μA
		Low-speed clock mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz FMR47 = 1	–	130	300	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz Program operation on RAM Flash memory off, FMSTP = 1	–	30	–	μA
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	–	25	70	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	–	23	55	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (high drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	–	3.8	–	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (low drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	–	2.0	–	μA
		Increase during A/D converter operation	Without sample & hold	–	0.9	–	mA
			With sample & hold	–	0.5	–	mA
		Stop mode	XIN clock off, T _{opr} = 25°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	–	0.7	3.0	μA
XIN clock off, T _{opr} = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	–		1.1	–	μA		

Timing requirements**(Unless Otherwise Specified: $V_{CC} = 3\text{ V}$, $V_{SS} = 0\text{ V}$ at $T_{\text{opr}} = 25^{\circ}\text{C}$) [$V_{CC} = 3\text{ V}$]****Table 5.24 XIN Input, XCIN Input**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(\text{XIN})}$	XIN input cycle time	100	–	ns
$t_{\text{WH}(\text{XIN})}$	XIN input "H" width	40	–	ns
$t_{\text{WL}(\text{XIN})}$	XIN input "L" width	40	–	ns
$t_{c(\text{XCIN})}$	XCIN input cycle time	14	–	μs
$t_{\text{WH}(\text{XCIN})}$	XCIN input "H" width	7	–	μs
$t_{\text{WL}(\text{XCIN})}$	XCIN input "L" width	7	–	μs

**Figure 5.12 XIN Input and XCIN Input Timing Diagram when $V_{CC} = 3\text{ V}$** **Table 5.25 TRAI0 Input**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(\text{TRAIO})}$	TRAIO input cycle time	300	–	ns
$t_{\text{WH}(\text{TRAIO})}$	TRAIO input "H" width	120	–	ns
$t_{\text{WL}(\text{TRAIO})}$	TRAIO input "L" width	120	–	ns

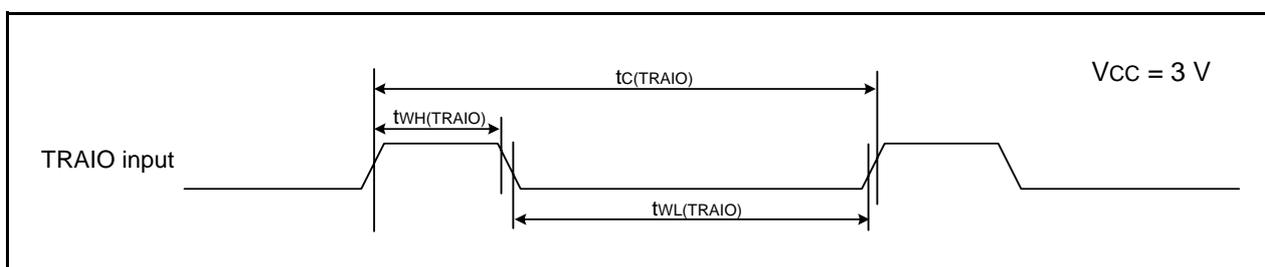
**Figure 5.13 TRAI0 Input Timing Diagram when $V_{CC} = 3\text{ V}$**

Table 5.26 Serial Interface

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(CK)}$	CLKi input cycle time	300	–	ns
$t_{w(CKH)}$	CLKi input “H” width	150	–	ns
$t_{w(CKL)}$	CLKi Input “L” width	150	–	ns
$t_{d(C-Q)}$	TXDi output delay time	–	80	ns
$t_{h(C-Q)}$	TXDi hold time	0	–	ns
$t_{su(D-C)}$	RXDi input setup time	70	–	ns
$t_{h(C-D)}$	RXDi input hold time	90	–	ns

i = 0 or 1

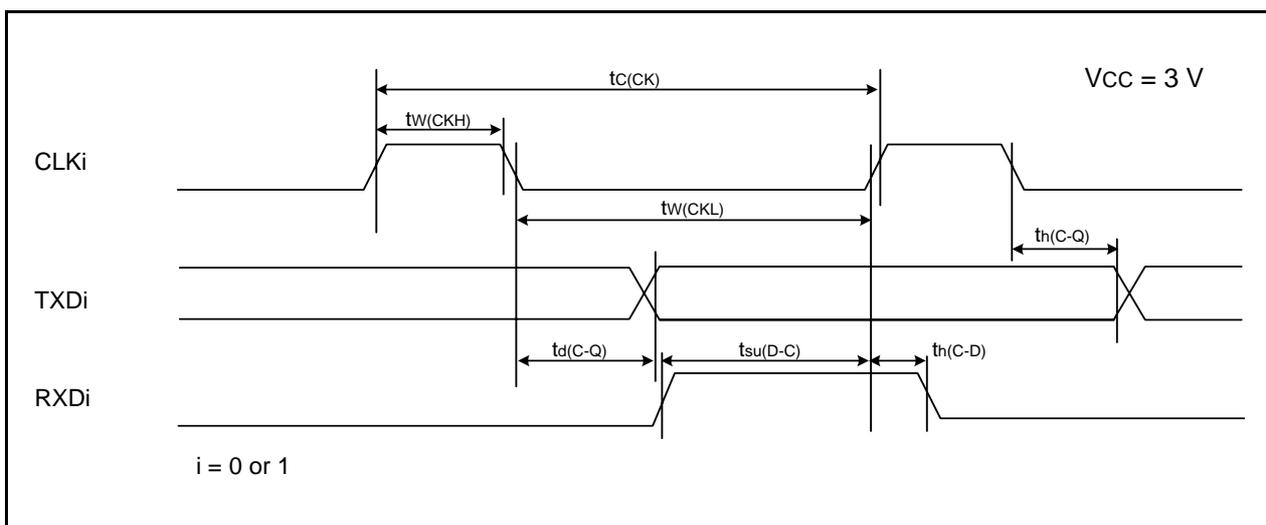


Figure 5.14 Serial Interface Timing Diagram when Vcc = 3 V

Table 5.27 External Interrupt \overline{INTi} (i = 0 to 3) Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(INH)}$	$\overline{INT0}$ input “H” width	380 ⁽¹⁾	–	ns
$t_{w(INL)}$	$\overline{INT0}$ input “L” width	380 ⁽²⁾	–	ns

NOTES:

1. When selecting the digital filter by the \overline{INTi} input filter select bit, use an \overline{INTi} input HIGH width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.
2. When selecting the digital filter by the \overline{INTi} input filter select bit, use an \overline{INTi} input LOW width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.

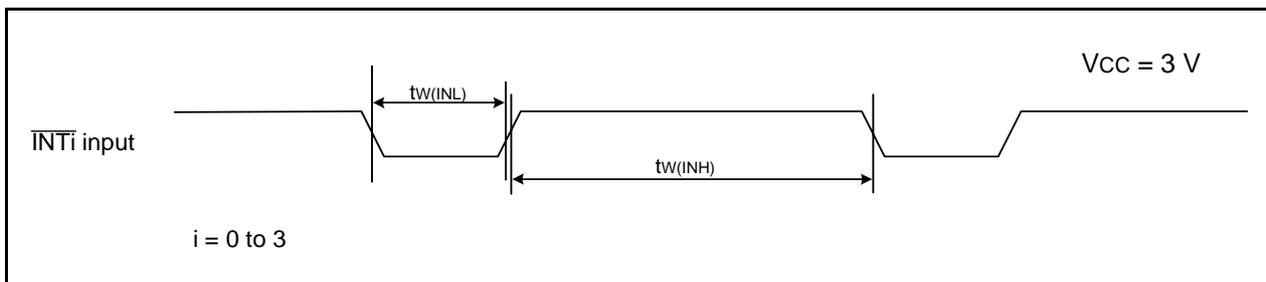


Figure 5.15 External Interrupt \overline{INTi} Input Timing Diagram when Vcc = 3 V

Table 5.28 Electrical Characteristics (5) [V_{CC} = 2.2 V]

Symbol	Parameter		Condition		Standard			Unit
					Min.	Typ.	Max.	
V _{OH}	Output "H" voltage	Except P2_0 to P2_7, XOUT	I _{OH} = -1 mA		V _{CC} - 0.5	–	V _{CC}	V
		P2_0 to P2_7	Drive capacity HIGH	I _{OH} = -2 mA	V _{CC} - 0.5	–	V _{CC}	V
			Drive capacity LOW	I _{OH} = -1 mA	V _{CC} - 0.5	–	V _{CC}	V
		XOUT	Drive capacity HIGH	I _{OH} = -0.1 mA	V _{CC} - 0.5	–	V _{CC}	V
			Drive capacity LOW	I _{OH} = -50 μA	V _{CC} - 0.5	–	V _{CC}	V
V _{OL}	Output "L" voltage	Except P2_0 to P2_7, XOUT	I _{OL} = 1 mA		–	–	0.5	V
		P2_0 to P2_7	Drive capacity HIGH	I _{OL} = 2 mA	–	–	0.5	V
			Drive capacity LOW	I _{OL} = 1 mA	–	–	0.5	V
		XOUT	Drive capacity HIGH	I _{OL} = 0.1 mA	–	–	0.5	V
			Drive capacity LOW	I _{OL} = 50 μA	–	–	0.5	V
V _{T+} -V _{T-}	Hysteresis	<u>INT0</u> , <u>INT1</u> , <u>INT2</u> , <u>INT3</u> , <u>KI0</u> , <u>KI1</u> , <u>KI2</u> , <u>KI3</u> , <u>TRAIO</u> , <u>RXD0</u> , <u>RXD1</u> , <u>CLK0</u> , <u>CLK1</u> , <u>SSI</u> , <u>SCL</u> , <u>SDA</u> , <u>SSO</u>			0.05	0.3	–	V
		<u>RESET</u>			0.05	0.15	–	V
I _{IH}	Input "H" current	V _I = 2.2 V		–	–	4.0	μA	
I _{IL}	Input "L" current	V _I = 0 V		–	–	-4.0	μA	
R _{PULLUP}	Pull-up resistance	V _I = 0 V		100	200	600	kΩ	
R _{FXIN}	Feedback resistance	XIN			–	5	–	MΩ
R _{FXCIN}	Feedback resistance	XCIN			–	35	–	MΩ
V _{RAM}	RAM hold voltage	During stop mode		1.8	–	–	V	

NOTE:

- V_{CC} = 2.2 V at T_{opr} = -20 to 85°C (N version) / -40 to 85°C (D version), f(XIN) = 5 MHz, unless otherwise specified.

REVISION HISTORY

R8C/24 Group, R8C/25 Group Datasheet

Rev.	Date	Description	
		Page	Summary
0.10	Feb 24, 2005	1 to 3 5, 6 5 to 7 8 9 13, 14 15 17 19 20	<p>Pin type changed: 48-pin(under consideration) → 52-pin.</p> <p>Package type revised: 48-pin LQFP(under consideration) → PLQP0052JA-A</p> <p>Table 1.5 TCLK added, VREF revised.</p> <p>Table 1.6 revised.</p> <p>Figures 3.1 and 3.2 part number revised.</p> <p>Tabel 4.1 revised: - 000Fh: 000XXXXXb → 00011111b - 0023h: FR0 → FRA0 - 0024h: FR1 → FRA1 - 0025h: FR2 → FRA2 - 0031h: Voltage Detection A Register 1, VC1 → Voltage Detection Register 1, VCA1 - 0032h: Voltage Detection A Register 2, VC2 → Voltage Detection Register 2, VCA2</p> <p>Tabel 4.3 Register name and the value after reset at 00B8h to 00BFh revised; NOTE2 added.</p> <p>Tabel 4.5 revised: - 0107h: LINSR → LINST - 0137h to 013Fh: Register symbol revised</p> <p>Tabel 4.6 revised: - 0140h to 015Fh: Register symbol revised - 0158h, 0159h: Timer RD General Register → Timer RD General Register A1</p>
0.20	Mar 8, 2005	2, 3 8 15	<p>Tables 1.1, 1.2 and 1.5 revised: "main clock" → "XIN clock"; "sub clock" → "XCIN clock"</p> <p>- 0023h to 0025h: 40MHz On-Chip Oscillator Control Register → High-Speed On-Chip Oscillator Control Register</p>
0.30	Sep 01, 2005	2, 3 4 5, 6	<p>Table 1.1 R8C/24 Group Performance, Table 1.2 R8C/25 Group Performance</p> <ul style="list-style-type: none"> • Serial Interface revised: <ul style="list-style-type: none"> - Serial Interface: 2 channels Clock synchronous serial I/O, UART - Clock Synchronous Serial Interface: 1 channel I²C bus Interface⁽¹⁾, Clock synchronous serial I/O with chip select <p>Figure 1.1 Block Diagram</p> <ul style="list-style-type: none"> • UART or Clock Synchronous Serial Interface: "(8 bits × 1 channel)" → "(8 bits × 2 channels)" revised • UART (8 bits × 1 channel) deleted <p>Table 1.3 Product Information of R8C/24 Group, Table 1.4 Product Information of R8C/25 Group "Flash Memory Version" → "N Version" revised</p>

REVISION HISTORY

R8C/24 Group, R8C/25 Group Datasheet

Rev.	Date	Description	
		Page	Summary
0.30	Sep 01, 2005	19	Tabel 4.5 SFR Information(5) revised: • 0118h : Timer RE Second Data Register/Counter Register → Timer RE Second Data Register/Counter Data Register
		20	Tabel 4.6 SFR Information(6) revised: • 0145h POCR0 → TRDPOCR0 • 0146h, 0147h TRDCNT0 → TRD0 • 0148h, 0149h GRA0 → TRDGRA0 • 014Ah, 014Bh GRB0 → TRDGRB0 • 014Ch, 014Dh GRC0 → TRDGRC0 • 014Eh, 014Fh GRD0 → TRDGRD0 • 0155h POCR1 → TRDPOCR1 • 0156h, 0157h TRDCNT1 → TRD1 • 0158h, 0159h GRA1 → TRDGRA1 • 015Ah, 015Bh GRB1 → TRDGRB1 • 015Ch, 015Dh GRC1 → TRDGRC1 • 015Eh, 015Fh GRD1 → TRDGRD1
		21	Tabel 4.7 SFR Information(7) revised: • 01B5h: 01000101b → 1000000Xb • 01B7h: XX000001b → 00000001b • FFFFh: (Note 2) added
		22 to 44	5. Electrical Characteristics added
0.40	Jan 24, 2006	all pages	• “Preliminary” deleted • Symbol name “TRDMDR” → “TRDMR”, “SSUAIC” → “SSUIC”, and “IIC2AIC” → “IICIC” revised • Pin name “TCLK” → “TRDCLK” revised
		2	Table 1.1 Functions and Specifications for R8C/24 Group revised
		3	Table 1.2 Functions and Specifications for R8C/25 Group revised
		4	Figure 1.1 Block Diagram; “Peripheral Functions” added, “System Clock Generation” → “System Clock Generator” revised
		5	Table 1.3 Product Information for R8C/24 Group revised
		6	Table 1.4 Product Information for R8C/25 Group revised
		7	Figure 1.4 Pin Assignments (Top View) “TCLK” → “TRDCLK” revised
		8	Table 1.5 Pin Functions “TCLK” → “TRDCLK” revised
		9	Table 1.6 Pin Name Information by Pin Number; “TCLK” → “TRDCLK” revised
		10	Figure 2.1 CPU Registers; “Reserved Area” → “Reserved Bit” revised
		12	2.8.10 Reserved Area; “Reserved Area” → “Reserved bit” revised
		13	Figure 3.1 Memory Map of R8C/24 Group; “Program area” → “program ROM” revised
		14	3.2 R8C/25 Group, Figure 3.2 Memory Map of R8C/25 Group; “Data area” → “data flash”, “Program area” → “program ROM” revised